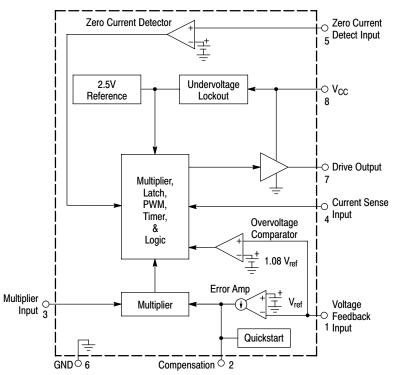
Power Factor Controllers

The MC34262/MC33262 are active power factor controllers specifically designed for use as a preconverter in electronic ballast and in off-line power converter applications. These integrated circuits feature an internal startup timer for stand-alone applications, a one quadrant multiplier for near unity power factor, zero current detector to ensure critical conduction operation, transconductance error amplifier, quickstart circuit for enhanced startup, trimmed internal bandgap reference, current sensing comparator, and a totem pole output ideally suited for driving a power MOSFET.

Also included are protective features consisting of an overvoltage comparator to eliminate runaway output voltage due to load removal, input undervoltage lockout with hysteresis, cycle—by—cycle current limiting, multiplier output clamp that limits maximum peak switch current, an RS latch for single pulse metering, and a drive output high state clamp for MOSFET gate protection. These devices are available in dual—in—line and surface mount plastic packages.

Features

- Overvoltage Comparator Eliminates Runaway Output Voltage
- Internal Startup Timer
- One Quadrant Multiplier
- Zero Current Detector
- Trimmed 2% Internal Bandgap Reference
- Totem Pole Output with High State Clamp
- Undervotage Lockout with 6.0 V of Hysteresis
- Low Startup and Or erating Current VV VV
- Supersedes Functionality of SG3561 and TDA4817
- Pb-Free Packages are Available







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POWER FACTOR CONTROLLERS

MARKING DIAGRAMS



PDIP-8 P SUFFIX CASE 626

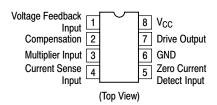






x = 3 or 4
A = Assembly Location
WL, L = Wafer Lot
YY, Y = Year
WW, W = Work Week
G = Pb-Free Package
Pb-Free Package

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 17 of this data sheet.

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Total Power Supply and Zener Current	$(I_{CC} + I_Z)$	30	mA
Output Current, Source or Sink (Note 1)	Io	500	mA
Current Sense, Multiplier, and Voltage Feedback Inputs	V _{in}	-1.0 to +10	V
Zero Current Detect Input High State Forward Current Low State Reverse Current	I _{in}	50 –10	mA
Power Dissipation and Thermal Characteristics P Suffix, Plastic Package, Case 626 Maximum Power Dissipation @ T _A = 70°C Thermal Resistance, Junction–to–Air D Suffix, Plastic Package, Case 751 Maximum Power Dissipation @ T _A = 70°C Thermal Resistance, Junction–to–Air	P _D R _{θJA} P _D R _{θJA}	800 100 450 178	mW °C/W mW °C/W
Operating Junction Temperature	TJ	+150	°C
Operating Ambient Temperature (Note 3) MC34262 MC33262	T _A	0 to + 85 - 40 to +105	°C
Storage Temperature	T _{stg}	- 65 to +150	°C

Maximum ratings are those values beyond which device damage can occur. Maximum ratings applied to the device are individual stress limit values (not normal operating conditions) and are not valid simultaneously. If these limits are exceeded, device functional operation is not implied, damage may occur and reliability may be affected.

ELECTRICAL CHARACTERISTICS ($V_{CC} = 12 \text{ V}$ (Note 2), for typical values $T_A = 25^{\circ}\text{C}$, for min/max values T_A is the operating ambient temperature range that applies (Note 3), unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
ERF OR AN PLIFER	חם		no:	+ / (1)	
Vollage Feedback In out Threshold	V =R				V
$T_A = 25^{\circ}C$		2.465	2.5	2.535	
$T_A = T_{low}$ to T_{high} ($V_{CC} = 12 \text{ V to } 28 \text{ V}$)		2.44	_	2.54	
Line Regulation (V_{CC} = 12 V to 28 V, T_A = 25°C)	Reg _{line}	_	1.0	10	mV
Input Bias Current (V _{FB} = 0 V)	I _{IB}	_	- 0.1	- 0.5	μΑ
Transconductance (T _A = 25°C)	9 _m	80	100	130	μmho
Output Current	Io				μΑ
Source (V _{FB} = 2.3 V)		_	10	_	
Sink $(V_{FB} = 2.7 V)$		_	10	-	
Output Voltage Swing					V
High State (V _{FB} = 2.3 V)	V _{OH(ea)}	5.8	6.4	_	
Low State ($V_{FB} = 2.7 \text{ V}$)	V _{OL(ea)}	_	1.7	2.4	
OVERVOLTAGE COMPARATOR					
Voltage Feedback Input Threshold	V _{FB(OV)}	1.065 V _{FB}	1.08 V _{FB}	1.095 V _{FB}	V
MULTIPLIER					
Input Bias Current, Pin 3 (V _{FB} = 0 V)	I _{IB}	_	- 0.1	- 0.5	μΑ
Input Threshold, Pin 2	V _{th(M)}	1.05 V _{OL(EA)}	1.2 V _{OL(EA)}	-	V

- Maximum package power dissipation limits must be observed.
 Adjust V_{CC} above the startup threshold before setting to 12 V.
 T_{low} = 0°C for MC34262 T_{high} = +85°C for MC34262 = +105°C for MC33262.

ELECTRICAL CHARACTERISTICS (continued) ($V_{CC} = 12 \text{ V (Note 5)}$, for typical values $T_A = 25^{\circ}\text{C}$, for min/max values T_A is the operating ambient temperature range that applies (Note 6), unless otherwise noted.)

Characteristic	Symbol	Min	Тур	Max	Unit
MULTIPLIER		•	•		•
Dynamic Input Voltage Range Multiplier Input (Pin 3) Compensation (Pin 2)	V _{Pin 3} V _{Pin 2}	0 to 2.5 V _{th(M)} to (V _{th(M)} + 1.0)	0 to 3.5 V _{th(M)} to (V _{th(M)} + 1.5)	- -	V
Multiplier Gain ($V_{Pin 3} = 0.5 \text{ V}$, $V_{Pin 2} = V_{th(M)} + 1.0 \text{ V}$) (Note 7)	K	0.43	0.65	0.87	1/V
ZERO CURRENT DETECTOR					
Input Threshold Voltage (V _{in} Increasing)	V_{th}	1.33	1.6	1.87	V
Hysteresis (V _{in} Decreasing)	V _H	100	200	300	mV
Input Clamp Voltage High State (I _{DET} = + 3.0 mA) Low State (I _{DET} = - 3.0 mA)	V _{IH} V _{IL}	6.1 0.3	6.7 0.7	_ 1.0	V
CURRENT SENSE COMPARATOR					
Input Bias Current (V _{Pin 4} = 0 V)	I _{IB}	_	- 0.15	-1.0	μΑ
Input Offset Voltage (V _{Pin 2} = 1.1 V, V _{Pin 3} = 0 V)	V _{IO}	-	9.0	25	mV
Maximum Current Sense Input Threshold (Note 8)	V _{th(max)}	1.3	1.5	1.8	٧
Delay to Output	t _{PHL(in/out)}	_	200	400	ns
DRIVE OUTPUT					
Output Voltage (V_{CC} = 12 V) Low State (I_{Sink} = 20 mA) (I_{Sink} = 200 mA) High State (I_{Source} = 20 mA) (I_{Source} = 200 mA)	V _{OL} V _{OH}	- - 9.8 7.8	0.3 2.4 10.3 8.4	0.8 3.3 -	V
Ou put Vol age (${}^{\prime}_{CC}$ = 3) V) High S ate ${}^{\prime}_{Source}$ = 20 mA, ${}^{\prime}_{C_L}$ = 15 p.F)	v) max	14	l ne	T / ₁₈	٧
Output Voltage Rise Time (C _L = 1.0 nF)	t _r	-	50	120	ns
Output Voltage Fall Time (C _L = 1.0 nF)	t _f	_	50	120	ns
Output Voltage with UVLO Activated $(V_{CC} = 7.0 \text{ V}, I_{Sink} = 1.0 \text{ mA})$	V _{O(UVLO)}	_	0.1	0.5	V
RESTART TIMER					
Restart Time Delay	t _{DLY}	200	620	_	μS
UNDERVOLTAGE LOCKOUT					
Startup Threshold (V _{CC} Increasing)	V _{th(on)}	11.5	13	14.5	V
Minimum Operating Voltage After Turn-On (V _{CC} Decreasing)	V _{Shutdown}	7.0	8.0	9.0	V
Hysteresis	V _H	3.8	5.0	6.2	V
TOTAL DEVICE					_
Power Supply Current Startup ($V_{CC} = 7.0 \text{ V}$) Operating Dynamic Operating (50 kHz, $C_L = 1.0 \text{ nF}$)	Icc	- - -	0.25 6.5 9.0	0.4 12 20	mA
Power Supply Zener Voltage (I _{CC} = 25 mA)	V_Z	30	36		V

^{4.} Maximum package power dissipation limits must be observed.
5. Adjust V_{CC} above the startup threshold before setting to 12 V.
6. T_{low} = 0°C for MC34262 T_{high} = +85°C for MC34262 = -40°C for MC33262 = +105°C for MC33262.
7. K = Pin 4 Threshold VPin 3 (VPin2 - Vth(M))
8. This parameter is measured with V_{FB} = 0 V, and V_{Pin 3} = 3.0 V.

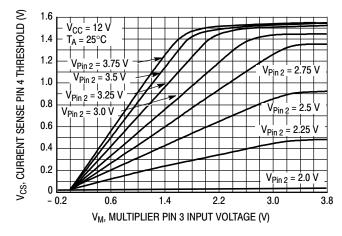


Figure 2. Current Sense Input Threshold versus Multiplier Input

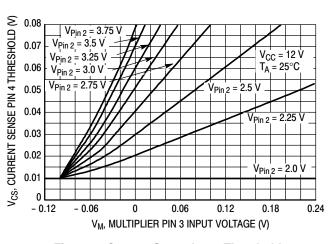


Figure 3. Current Sense Input Threshold versus Multiplier Input, Expanded View

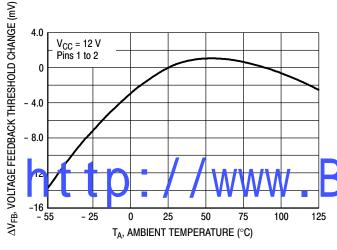


Figure 4. Voltage Feedback Input Threshold Change versus Temperature

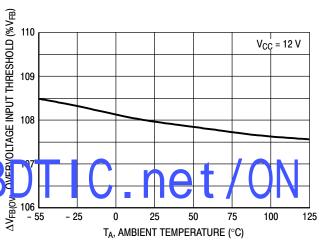


Figure 5. Overvoltage Comparator Input Threshold versus Temperature

 $V_{CC} = 12 V$

R_L = 100 k

 $C_{L}^{-} = 2.0 \text{ pF}$

T_A = 25°Ċ

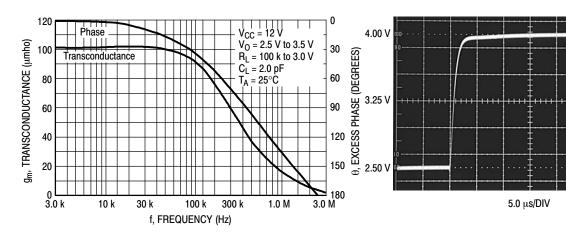


Figure 6. Error Amp Transconductance and Phase versus Frequency

Figure 7. Error Amp Transient Response

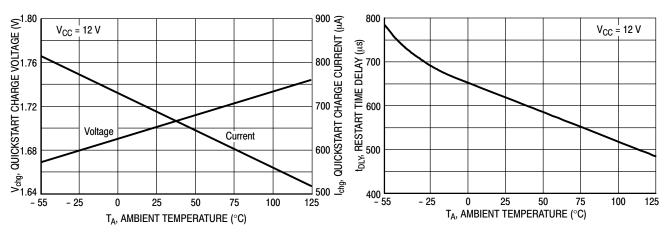


Figure 8. Quickstart Charge Current versus Temperature

Figure 9. Restart Timer Delay versus Temperature

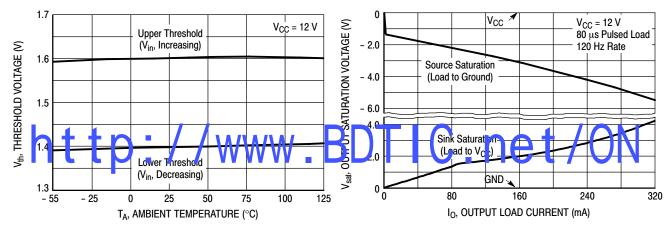


Figure 10. Zero Current Detector Input Threshold Voltage versus Temperature

Figure 11. Output Saturation Voltage versus Load Current

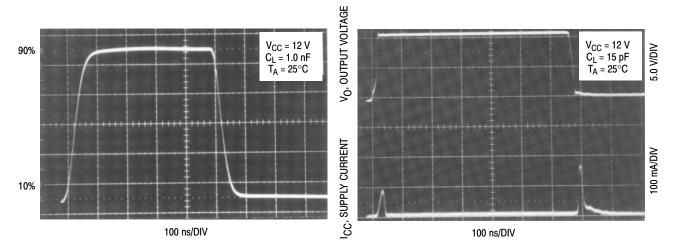


Figure 12. Drive Output Waveform

Figure 13. Drive Output Cross Conduction

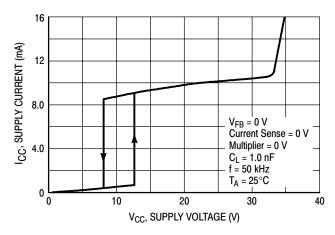


Figure 14. Supply Current versus Supply Voltage

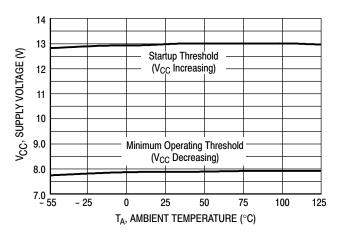


Figure 15. Undervoltage Lockout Thresholds versus Temperature

FUNCTIONAL DESCRIPTION

Introduction

With the goal of exceeding the requirements of legislation on line-current harmonic content, there is an ever increasing demand for an economical method of obtaining a unity power factor. This data sheet describes a monolithic control IC that was specifically designed for power factor control with minimal external components. It offers the designer a simple, cost-effective solution to obtain the benefits of active power factor correction.

Most electronic ballists and switching power stipplies use a bridge rectrife and a bulk storage capacitor to derive raw do voltage from the utility ac line, Figure 15.

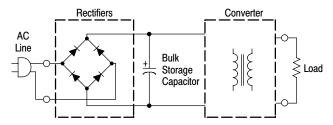


Figure 16. Uncorrected Power Factor Circuit

This simple rectifying circuit draws power from the line when the instantaneous ac voltage exceeds the capacitor voltage. This occurs near the line voltage peak and results in a high charge current spike, Figure 16. Since power is only taken near the line voltage peaks, the resulting spikes of current are extremely nonsinusoidal with a high content of harmonics. This results in a poor power factor condition where the apparent input power is much higher than the real power. Power factor ratios of 0.5 to 0.7 are common.

Power factor correction can be achieved with the use of either a passive or an active input circuit. Passive circuits usually contain a combination of large capacitors, inductors, and rectifiers that operate at the ac line frequency. Active circuits incorporate some form of a high

frequency switching converter for the power processing, with the boost converter being the most popular topology, Figure 17. Since active input circuits operate at a frequency much higher than that of the ac line, they are smaller, lighter in weight, and more efficient than a passive circuit that yields similar results. With proper control of the preconverter, almost any complex load can be made to appear resistive to the ac line, thus significantly reducing

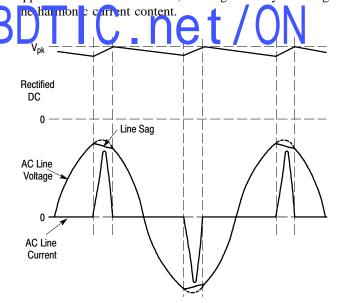


Figure 17. Uncorrected Power Factor Input Waveforms

The MC34262, MC33262 are high performance, critical conduction, current-mode power factor controllers specifically designed for use in off-line active preconverters. These devices provide the necessary features required to significantly enhance poor power factor loads by keeping the ac line current sinusoidal and in phase with the line voltage.

Operating Description

The MC34262, MC33262 contain many of the building blocks and protection features that are employed in modern high performance current mode power supply controllers. There are, however, two areas where there is a major difference when compared to popular devices such as the

UC3842 series. Referring to the block diagram in Figure 19, note that a multiplier has been added to the current sense loop and that this device does not contain an oscillator. The reasons for these differences will become apparent in the following discussion. A description of each of the functional blocks is given below.

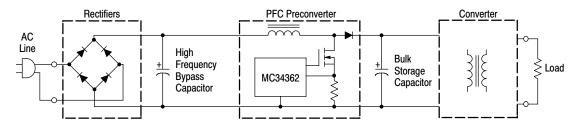


Figure 18. Active Power Factor Correction Preconverter

Error Amplifier

An Error Amplifier with access to the inverting input and output is provided. The amplifier is a transconductance type, meaning that it has high output impedance with controlled voltage-to-current gain. The amplifier features a typical gm of 100 µmhos (Figure 5). The noninverting input is internally biased at 2.5 V \pm 2.0% and is not pinned out. The output voltage of the power factor converter is typically divided down and monitored by the inverting input. The maximum input bias current is $-0.5 \mu A$, which can cau e a l'out but sol age error that is equal to the product of the input bias current and the value of the upper divider resistor R₂. The Error Amp output is internally connected to the Multiplier and is pinned out (Pin 2) for external loop compensation. Typically, the bandwidth is set below 20 Hz, so that the amplifier's output voltage is relatively constant over a given ac line cycle. In effect, the error amp monitors the average output voltage of the converter over several line cycles. The Error Amp output stage was designed to have a relatively constant transconductance over temperature. This allows the designer to define the compensated bandwidth over the intended operating temperature range. The output stage can sink and source 10 μA of current and is capable of swinging from 1.7 V to 6.4 V, assuring that the Multiplier can be driven over its entire dynamic range.

A key feature to using a transconductance type amplifier, is that the input is allowed to move independently with respect to the output, since the compensation capacitor is connected to ground. This allows dual usage of the Voltage Feedback Input pin by the Error Amplifier and by the Overvoltage Comparator.

Overvoltage Comparator

An Overvoltage Comparator is incorporated to eliminate the possibility of runaway output voltage. This condition can occur during initial startup, sudden load removal, or during output arcing and is the result of the low bandwidth that must be used in the Error Amplifier control loop. The Overvoltage Comparator monitors the peak output voltage of the converter, and when exceeded, immediately terminates MOSFET switching. The comparator threshold is internally set to 1.08 V_{ref}. In order to prevent false tripping during normal operation, the value of the output filter capacitor C₃ must be large enough to keep the peak upple less than 16% of the average do output. The Overvoltage Convar tor input to Drive Output can—off propagation delay is typically 450 ns. A comparison of startup overshoot without and with the Overvoltage Comparator circuit is shown in Figure 23.

Multiplier

A single quadrant, two input multiplier is the critical element that enables this device to control power factor. The ac full wave rectified haversines are monitored at Pin 3 with respect to ground while the Error Amp output at Pin 2 is monitored with respect to the Voltage Feedback Input threshold. The Multiplier is designed to have an extremely linear transfer curve over a wide dynamic range, 0 V to 3.2 V for Pin 3, and 2.0 V to 3.75 V for Pin 2, Figure 1. The Multiplier output controls the Current Sense Comparator threshold as the ac voltage traverses sinusoidally from zero to peak line, Figure 18. This has the effect of forcing the MOSFET on-time to track the input line voltage, resulting in a fixed Drive Output on-time, thus making the preconverter load appear to be resistive to the ac line. An approximation of the Current Sense Comparator threshold can be calculated from the following equation. This equation is accurate only under the given test condition stated in the electrical table.

 V_{CS} , Pin 4 Threshold $\approx 0.65 (V_{Pin 2} - V_{th(M)}) V_{Pin 3}$

A significant reduction in line current distortion can be attained by forcing the preconverter to switch as the ac line voltage crosses through zero. The forced switching is achieved by adding a controlled amount of offset to the Multiplier and Current Sense Comparator circuits. The equation shown below accounts for the built—in offsets and is accurate to within ten percent. Let $V_{th(M)} = 1.991~V$

$$V_{CS}$$
, Pin 4 Threshold = 0.544 ($V_{Pin 2} - V_{th(M)}$) $V_{Pin 3}$
+ 0.0417 ($V_{Pin 2} - V_{th(M)}$)

Zero Current Detector

The MC34262 operates as a critical conduction current mode controller, whereby output switch conduction is initiated by the Zero Current Detector and terminated when the peak inductor current reaches the threshold level established by the Multiplier output. The Zero Current Detector initiates the next on–time by setting the RS Latch at the instant the inductor current reaches zero. This critical conduction mode of operation has two significant benefits. First, since the MOSFET cannot turn–on until the inductor current reaches zero, the output rectifier reverse recovery time becomes less critical, allowing the use of an inexpensive rectifier. Second, since there are no deadtime gaps between cycles, the ac line current is continuous, thus limiting the peak switch to twice the average input current.

The Zero Current Detector indirectly senses the inductor current by monitoring when the auxiliary winding voltage falls below 1.4 V. To prevent false tripping, 200 mV of hysteresis is provided. Figure 9 shows that the thresholds are vell-defined over temperature. The Zero Aturent Detector input is in ernally protected by two clamps. The upper 6.7 V clamp prevents input overvoltage breakdown while the lower 0.7 V clamp prevents substrate injection. Current limit protection of the lower clamp transistor is provided in the event that the input pin is accidentally shorted to ground. The Zero Current Detector input to Drive Output turn—on propagation delay is typically 320 ns.

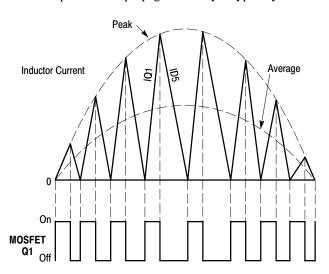


Figure 19. Inductor Current and MOSFET Gate Voltage Waveforms

Current Sense Comparator and RS Latch

The Current Sense Comparator RS Latch configuration used ensures that only a single pulse appears at the Drive Output during a given cycle. The inductor current is converted to a voltage by inserting a ground–referenced sense resistor R_7 in series with the source of output switch Q1. This voltage is monitored by the Current Sense Input and compared to a level derived from the Multiplier output. The peak inductor current under normal operating conditions is controlled by the threshold voltage of Pin 4 where:

$$I_{L(pk)} = \frac{Pin 4 Threshold}{R_7}$$

Abnormal operating conditions occur during preconverter startup at extremely high line or if output voltage sensing is lost. Under these conditions, the Multiplier output and Current Sense threshold will be internally clamped to 1.5 V. Therefore, the maximum peak switch current is limited to:

$$I_{pk(max)} = \frac{1.5 \text{ V}}{R_7}$$

An internal RC filter has been included to attenuate any high frequency noise that may be present on the current waveform. This filter helps reduce the ac line current distortion especially near the zero crossings. With the component values shown in Figure 20, the Current Sense Comparator threshold, at the peak of the haversine varies from 1.1 V at 90 Vac to 100 mV at 268 Vac. The Current Sense input to Drive Out out turn-of proragation delay is voically less than 200 ns.

Timer

A watchdog timer function was added to the IC to eliminate the need for an external oscillator when used in stand-alone applications. The Timer provides a means to automatically start or restart the preconverter if the Drive Output has been off for more than 620 µs after the inductor current reaches zero. The restart time delay versus temperature is shown in Figure 8.

Undervoltage Lockout and Quickstart

An Undervoltage Lockout comparator has been incorporated to guarantee that the IC is fully functional before enabling the output stage. The positive power supply terminal (V_{CC}) is monitored by the UVLO comparator with the upper threshold set at 13 V and the lower threshold at 8.0 V. In the stand-by mode, with V_{CC} at 7.0 V, the required supply current is less than 0.4 mA. This large hysteresis and low startup current allow the implementation of efficient bootstrap startup techniques, making these devices ideally suited for wide input range off-line preconverter applications. An internal 36 V clamp has been added from V_{CC} to ground to protect the IC and capacitor C₄ from an overvoltage condition. This feature is desirable if external circuitry is used to delay the startup of the preconverter. The supply current, startup, and operating voltage characteristics are shown in Figures 13 and 14.

A Quickstart circuit has been incorporated to optimize converter startup. During initial startup, compensation capacitor C_1 will be discharged, holding the error amp output below the Multiplier threshold. This will prevent Drive Output switching and delay bootstrapping of capacitor C_4 by diode D_6 . If Pin 2 does not reach the multiplier threshold before C_4 discharges below the lower UVLO threshold, the converter will "hiccup" and experience a significant startup delay. The Quickstart circuit is designed to precharge C_1 to 1.7 V, Figure 7. This level is slightly below the Pin 2 Multiplier threshold, allowing immediate Drive Output switching and bootstrap operation when C_4 crosses the upper UVLO threshold.

Drive Output

The MC34262/MC33262 contain a single totem-pole output stage specifically designed for direct drive of power

MOSFETs. The Drive Output is capable of up to ± 500 mA peak current with a typical rise and fall time of 50 ns with a 1.0 nF load. Additional internal circuitry has been added to keep the Drive Output in a sinking mode whenever the Undervoltage Lockout is active. This characteristic eliminates the need for an external gate pulldown resistor. The totem–pole output has been optimized to minimize cross–conduction current during high speed operation. The addition of two 10 Ω resistors, one in series with the source output transistor and one in series with the sink output transistor, helps to reduce the cross–conduction current and radiated noise by limiting the output rise and fall time. A 16 V clamp has been incorporated into the output stage to limit the high state V_{OH} . This prevents rupture of the MOSFET gate when V_{CC} exceeds 20 V.

APPLICATIONS INFORMATION

The application circuits shown in Figures 19, 20 and 21 reveal that few external components are required for a complete power factor preconverter. Each circuit is a peak detecting current—mode boost converter that operates in critical conduction mode with a fixed on—time and variable off—time. A major benefit of critical conduction operation is that the current loop is inherently stable, thus eliminating the need for ramp compensation. The application in Figure 19 t pera es ever an input voltage rulge of 90 Yac to 138 /ac and provides in output power of 30 W (13) V at 350 mA) with an associated power factor of approximately

0.998 at nominal line. Figures 20 and 21 are universal input preconverter examples that operate over a continuous input voltage range of 90 Vac to 268 Vac. Figure 20 provides an output power of 175 W (400 V at 440 mA) while Figure 21 provides 450 W (400 V at 1.125 A). Both circuits have an observed worst–case power factor of approximately 0.989. The input current and voltage waveforms of Figure 20 are shown in Figure 22 with operation at 115 Vac and 230 Vac. The data for each of the approximately via high the est set–up though Figure 2.

Table 1. Design Equations

Notes	Calculation	Formula
Calculate the maximum required output power.	Required Converter Output Power	$P_O = V_O I_O$
Calculated at the minimum required ac line voltage for output regulation. Let the efficiency η = 0.92 for low line operation.	Peak Inductor Current	$I_{L(pk)} = \frac{2\sqrt{2} P_O}{\eta Vac_{(LL)}}$
Let the switching cycle $t=40~\mu s$ for universal input (85 to 265 Vac) operation and 20 μs for fixed input (92 to 138 Vac, or 184 to 276 Vac) operation.	Inductance	$L_{P} = \frac{t \left(\frac{V_{O}}{\sqrt{2}} - Vac_{(LL)}\right) \eta Vac_{(LL)}^{2}}{\sqrt{2} V_{O} P_{O}}$
In theory the on–time t_{on} is constant. In practice t_{on} tends to increase at the ac line zero crossings due to the charge on capacitor C_5 . Let $Vac = Vac_{(LL)}$ for initial t_{on} and t_{off} calculations.	Switch On-Time	$t_{on} = \frac{2 P_O L_P}{\eta Vac^2}$
The off–time t_{off} is greatest at the peak of the ac line voltage and approaches zero at the ac line zero crossings. Theta (θ) represents the angle of the ac line voltage.	Switch Off-Time	$t_{off} = \frac{t_{on}}{\frac{V_O}{\sqrt{2} \text{ Vac } \text{Sin } \theta }} - 1$
The minimum switching frequency occurs at the peak of the ac line voltage. As the ac line voltage traverses from peak to zero, t _{off} approaches zero producing an increase in switching frequency.	Switching Frequency	$f = \frac{1}{t_{on} + t_{off}}$
Set the current sense threshold $V_{\rm CS}$ to 1.0 V for universal input (85 Vac to 265 Vac) operation and to 0.5 V for fixed input (92 Vac to 138 Vac, or 184 Vac to 276 Vac) operation. Note that $V_{\rm CS}$ must be <1.4 V.	Peak Switch Current	$R_7 = \frac{V_{CS}}{I_{L(pk)}}$
Set the multiplier input voltage V_M to 3.0 V at high line. Empirically adjust V_M for the lowest distortion over the abline vollage range while quantifieding startur at minimum line.	/ Multip ier in out 'olt ige	
The I_{IB} R_{1} error term can be minimized with a divider current in excess of 50 $\mu A.$	Converter Output Voltage	$V_{O} = V_{ref} \left(\frac{R_2}{R_1} + 1 \right) - I_{IB} R_2$
The calculated peak–to–peak ripple must be less than 16% of the average dc output voltage to prevent false tripping of the Overvoltage Comparator. Refer to the Overvoltage Comparator text. ESR is the equivalent series resistance of C ₃ .	Converter Output Peak to Peak Ripple Voltage	$\Delta V_{O(pp)} = I_O \sqrt{\left(\frac{1}{2\pi f_{ac} C_3}\right)^2 + ESR^2}$
The bandwidth is typically set to 20 Hz. When operating at high ac line, the value of C_1 may need to be increased. (See Figure 25)	Error Amplifier Bandwidth	$BW = \frac{gm}{2 \pi C_1}$

The following converter characteristics must be chosen:

 $\label{eq:VO} \begin{array}{ll} \text{V}_{\text{O}} - \text{Desired output voltage} & \text{Vac} - \text{AC RMS line voltage} \\ \text{I}_{\text{O}} - \text{Desired output current} & \text{Vac}_{\text{(LL)}} - \text{AC RMS low line voltage} \end{array}$

 ΔV_O – Converter output peak–to–peak ripple voltage

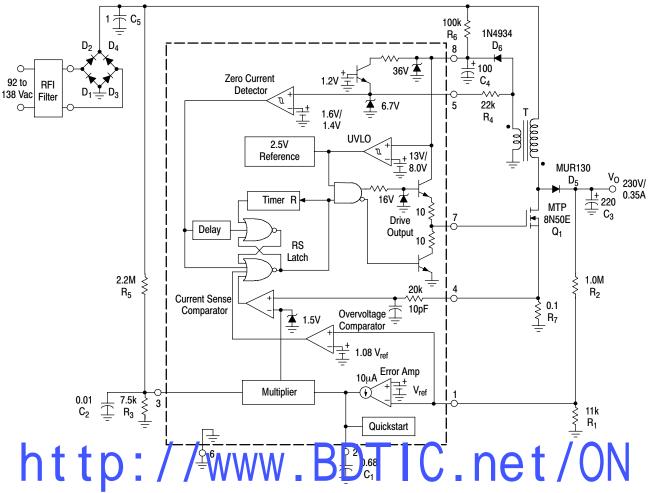


Figure 20. 80 W Power Factor Controller

Power Factor Controller Test Data

	AC Line Input								D	C Outpu	t		
				Cur	rent Harm	onic Disto	rtion (% I _f	und)					
V_{rms}	P_{in}	PF	I_{fund}	THD	2	3	5	7	V _{O(pp)}	V_{O}	I_{O}	P_{O}	η(%)
90	85.9	0.999	0.93	2.6	0.08	1.6	0.84	0.95	4.0	230.7	0.350	80.8	94.0
100	85.3	0.999	0.85	2.3	0.13	1.0	1.2	0.73	4.0	230.7	0.350	80.8	94.7
110	85.1	0.998	0.77	2.2	0.10	0.58	1.5	0.59	4.0	230.7	0.350	80.8	94.9
120	84.7	0.998	0.71	3.0	0.09	0.73	1.9	0.58	4.1	230.7	0.350	80.8	95.3
130	84.4	0.997	0.65	3.9	0.12	1.7	2.2	0.61	4.1	230.7	0.350	80.8	95.7
138	84.1	0.996	0.62	4.6	0.16	2.4	2.3	0.60	4.1	230.7	0.350	80.8	96.0

This data was taken with the test set-up shown in Figure 24.

T = Coilcraft N2881-A

Primary: 62 turns of # 22 AWG Secondary: 5 turns of # 22 AWG Core: Coilcraft PT2510, EE 25

Gap: 0.072" total for a primary inductance (Lp) of 320 μH Heatsink = AAVID Engineering Inc. 590302B03600, or 593002B03400

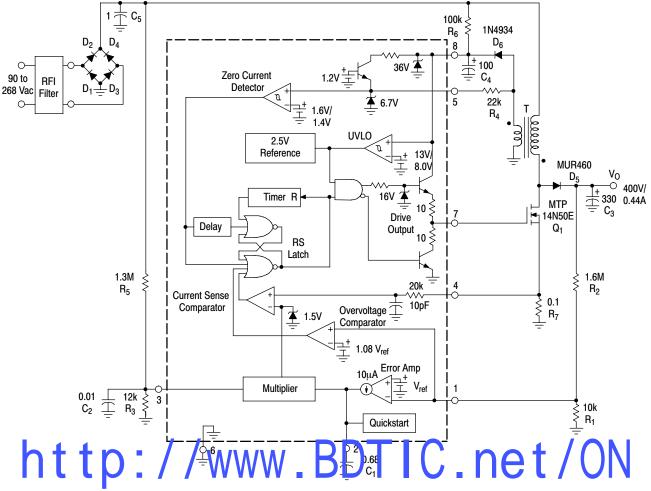


Figure 21. 175 W Universal Input Power Factor Controller

Power Factor Controller Test Data

	AC Line Input								D	C Outpu	ıt		
				Cur	rent Harm	onic Disto	rtion (% I _f	und)					
V_{rms}	P_{in}	PF	I_{fund}	THD	2	3	5	7	V _{O(pp)}	V_{O}	I_{O}	P_{O}	η(%)
90	193.3	0.991	2.15	2.8	0.18	2.6	0.55	1.0	3.3	402.1	0.44	176.9	91.5
120	190.1	0.998	1.59	1.6	0.10	1.4	0.23	0.72	3.3	402.1	0.44	176.9	93.1
138	188.2	0.999	1.36	1.2	0.12	1.3	0.65	0.80	3.3	402.1	0.44	176.9	94.0
180	184.9	0.998	1.03	2.0	0.10	0.49	1.2	0.82	3.4	402.1	0.44	176.9	95.7
240	182.0	0.993	0.76	4.4	0.09	1.6	2.3	0.51	3.4	402.1	0.44	176.9	97.2
268	180.9	0.989	0.69	5.9	0.10	2.3	2.9	0.46	3.4	402.1	0.44	176.9	97.8

This data was taken with the test set-up shown in Figure 24.

T = Coilcraft N2880-A

Primary: 78 turns of # 16 AWG Secondary: 6 turns of # 18 AWG Core: Coilcraft PT4215, EE 42–15

Gap: 0.104" total for a primary inductance (LP) of 870 μH

Heatsink = AAVID Engineering Inc. 590302B03600

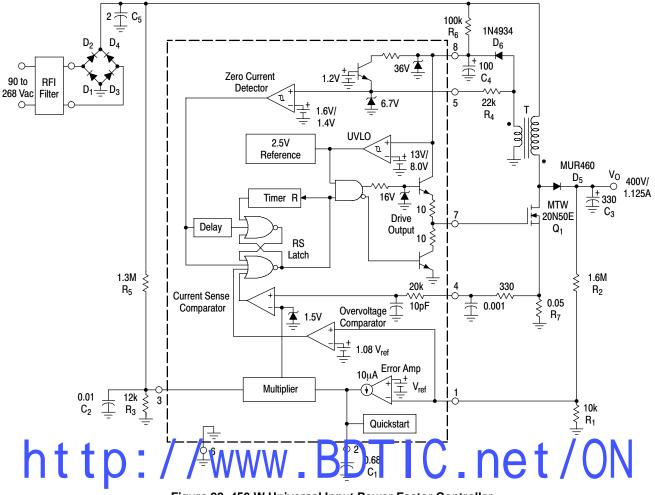


Figure 22. 450 W Universal Input Power Factor Controller

Power Factor Controller Test Data

	AC Line Input							D	C Outpu	ıt			
				Cur	rent Harm	onic Disto	rtion (% I _f	und)					
V_{rms}	Pin	PF	I_{fund}	THD	2	3	5	7	V _{O(pp)}	V_{O}	Io	Po	η(%)
90	489.5	0.990	5.53	2.2	0.10	1.5	0.25	0.83	8.8	395.5	1.14	450.9	92.1
120	475.1	0.998	3.94	2.5	0.12	0.29	0.62	0.52	8.8	395.5	1.14	450.9	94.9
138	470.6	0.998	3.38	2.1	0.06	0.70	1.1	0.41	8.8	395.5	1.14	450.9	95.8
180	463.4	0.998	2.57	4.1	0.21	2.0	1.6	0.71	8.9	395.5	1.14	450.9	97.3
240	460.1	0.996	1.91	4.8	0.14	4.3	2.2	0.63	8.9	395.5	1.14	450.9	98.0
268	459.1	0.995	1.72	5.8	0.10	5.0	2.5	0.61	8.9	395.5	1.14	450.9	98.2

This data was taken with the test set-up shown in Figure 24.

T = Coilcraft P3657-A

Primary: 38 turns Litz wire, 1300 strands of #48 AWG, Kerrigan-Lewis, Chicago, IL

Secondary: 3 turns of # 20 AWG

Core: Coilcraft PT4220, EE 42-20

Gap: 0.180" total for a primary inductance (L_P) of 190 μH

Heatsink = AAVID Engineering Inc. 604953B04000 Extrusion

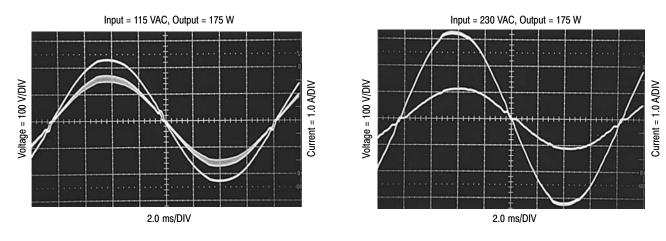


Figure 23. Power Factor Corrected Input Waveforms (Figure 20 Circuit)

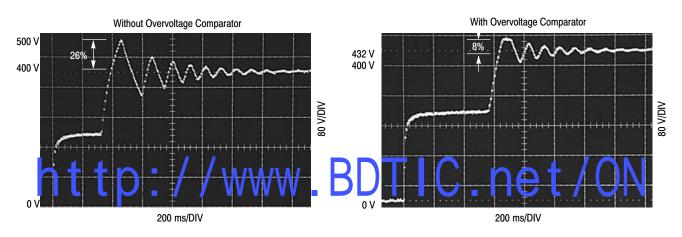


Figure 24. Output Voltage Startup Overshoot (Figure 20 Circuit)

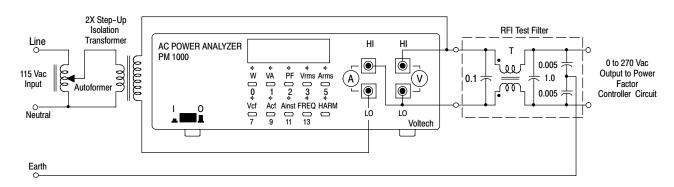


Figure 25. Power Factor Test Set-Up

An RFI filter is required for best performance when connecting the preconverter directly to the ac line. The filter attenuates the level of high frequency switching that appears on the ac line current waveform. Figures 19 and 20 work well with commercially available two stage filters such as the Delta Electronics 03DPCG5. Shown above is a single stage test filter that can easily be constructed with four ac line rated capacitors and a common–mode transformer. Coilcraft CMT3–28–2 was used to test Figures 19 and 20. It has a minimum inductance of 28 mH and a maximum current rating of 2.0 A. Coilcraft CMT4–17–9 was used to test Figure 21. It has a minimum inductance of 17 mH and a maximum current rating of 9.0 A. Circuit conversion efficiency η (%) was calculated without the power loss of the RFI filter.

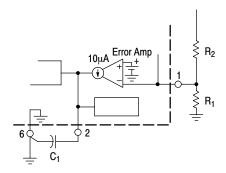


Figure 26. Error Amp Compensation

The Error Amp output is a high impedance node and is susceptible to noise pickup. To minimize pickup, compensation capacitor C_1 must be connected as close to Pin 2 as possible with a short, heavy ground returning directly to Pin 6. When operating at high ac line, the voltage at Pin 2 may approach the lower threshold of the Multiplier, ≈ 2.0 V. If there is excessive ripple on Pin 2, the Multiplier will be driven into cut–off causing circuit instability, high distortion and poor power factor. This problem can be eliminated by increasing the value of C_1 .

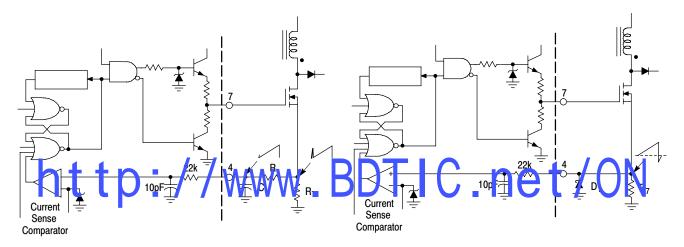
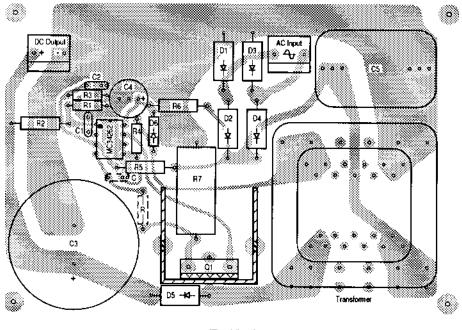


Figure 27. Current Waveform Spike Suppression

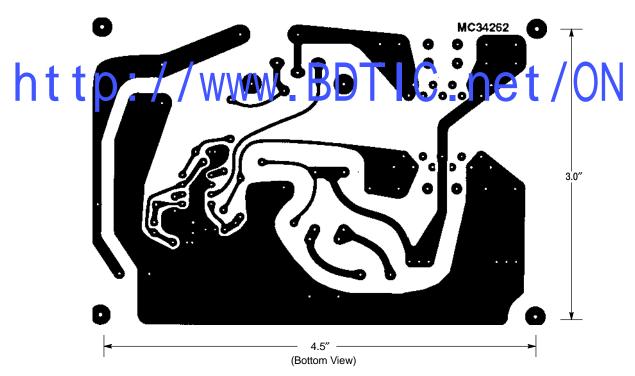
A narrow turn–on spike is usually present on the leading edge of the current waveform and can cause circuit instability. The MC34262 provides an internal RC filter with a time constant of 220 ns. An additional external RC filter may be required in universal input applications that are above 200 W. It is suggested that the external filter be placed directly at the Current Sense Input and have a time constant that approximates the spike duration.

Figure 28. Negative Current Waveform Spike Suppression

A negative turn–off spike can be observed on the trailing edge of the current waveform. This spike is due to the parasitic inductance of resistor R_7 , and if it is excessive, it can cause circuit instability. The addition of Schottky diode D_1 can effectively clamp the negative spike. The addition of the external RC filter shown in Figure 26 may provide sufficient spike



(Top View)



NOTE: Use 2 oz. copper laminate for optimum circuit performance.

Figure 29. Printed Circuit Board and Component Layout (Circuits of Figures 20 and 21)

DEVICE ORDERING INFORMATION

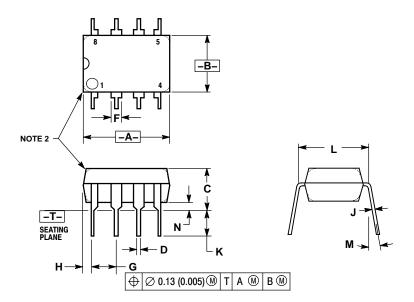
Device	Operating Temperature Range	Package	Shipping [†]
MC34262D		SOIC-8	98 Units / Rail
MC34262DG	T 000 0500	SOIC-8 (Pb-Free)	98 Units / Rail
MC34262DR2	$T_A = 0^{\circ}C \text{ to } +85^{\circ}C$	SOIC-8	2500 / Tape & Reel
MC34262DR2G		SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC34262P		PDIP-8	50 Units / Rail
MC34262PG	$T_A = 0$ °C to +85°C	PDIP-8 (Pb-Free)	50 Units / Rail
MC33262D		SOIC-8	98 Units / Rail
MC33262DG		SOIC-8 (Pb-Free)	98 Units / Rail
MC33262DR2		SOIC-8	2500 / Tape & Reel
MC33262DR2G	T 4000 to :40500	SOIC-8 (Pb-Free)	2500 / Tape & Reel
MC33262P	$T_A = -40^{\circ}\text{C to } +105^{\circ}\text{C}$	PDIP-8	50 Units / Rail
MC33262PG		PDIP-8 (Pb-Free)	50 Units / Rail
MC33262CDR2		SOIC-8	2500 / Tape & Reel
MC33262CDR2G		SOIC-8 (Pb-Free)	2500 / Tape & Reel

tFor information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

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PACKAGE DIMENSIONS

PDIP-8 **P SUFFIX** PLASTIC PACKAGE CASE 626-05 ISSUE L



NOTES:

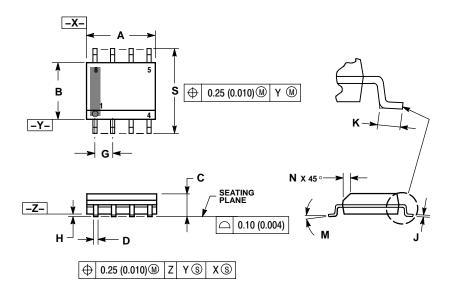
- 1. DIMENSION L TO CENTER OF LEAD WHEN
- FORMED PARALLEL.
 PACKAGE CONTOUR OPTIONAL (ROUND OR SQUARE CORNERS).
 DIMENSIONING AND TOLERANCING PER ANSI
- Y14.5M, 1982.

	MILLIN	METERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	9.40	10.16	0.370	0.400	
В	6.10	6.60	0.240	0.260	
С	3.94	4.45	0.155	0.175	
D	0.38	0.51	0.015	0.020	
F	1.02	1.78	0.040	0.070	
G	2.54	BSC	0.100 BSC		
Н	0.76	1.27	0.030	0.050	
J	0.20	0.30	0.008	0.012	
K	2.92	3.43	0.115	0.135	
L	7.62	BSC	0.300	BSC	
M		10°		10°	
N	0.76	1.01	0.030	0.040	

http://www.BDTIC.net/ON

PACKAGE DIMENSIONS

SOIC-8 D SUFFIX PLASTIC PACKAGE CASE 751-07 ISSUE AG

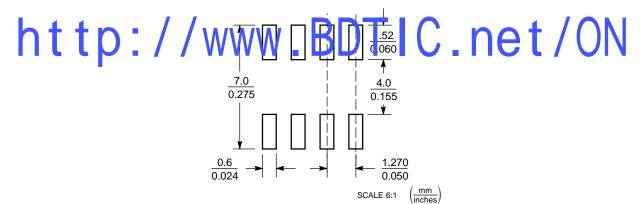


NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
- 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
- 5. DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
- 751–01 THRU 751–06 ARE OBSOLETE. NEW STANDARD IS 751–07.

	MILLIN	IETERS	INC	HES	
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27	7 BSC	0.050 BSC		
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016	0.050	
М	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0 244	

SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

The products described herein (MC34262, MC33262), may be covered by the following U.S. patent: 5,073,850. There may be other patents pending.

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